## MITSUBISHI SEMICONDUCTOR < GaAs HBT>

**BA01203** 

GaAs HBT HYBRID IC

Specifications are subject to change without notice.

### **DESCRIPTION**

BA01203 is GaAs RF amplifier designed for **CDMA/AMPS** handheld-phone.

## **FEATURES**

High gain Gp=28dB Single supply voltage Vcc=3.2V

CDMA-mode

High power Po=28.5dBm High efficiency Ict=580mA(38%)

AMPS-mode

High power Po=31dBm(@Vcc=3.2V)

High efficiency Ict=820mA(@Po=31dBm,Vcc=3.2V)

Internal input and output matching Small size: 6x6mm<sup>2</sup>

#### **APPLICATION**

CDMA/AMPS 824-849MHz handset.

# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

ABSOLUTE MAXIMUM HATINGS (Ta=25 C)									
Symbol	Parameter	Condition	Ratings	Unit					
Vcc	Corrector voltage		5	V					
Pin	Input Power	ZG=ZL=50Ω	5	dBm					
Tc(op)	Operating case temp.		-30~+95	°C					
Tstg	Storage temp.		-30~+125	°C					

Each maximum rating is guaranteed independently.

## ELECTRICAL CHARACTERISTICS (Ta=25°C, Recommendation of operation voltage=3.2-4.2V)

Symbol	Parameter	Condition Note1	MIN	Limits TYP	MAX	Unit
freq	Frequency(TDMA/AMPS)		824		849	MHz
Iq	Quiescent Current	No-RF input Vc=3.2V,Vref=3.0V		75		mA
Pin	Input Power	CDMA-mode <sup>(note2)</sup>		1		dBm
lct	Total Corrector Current	Po=28.5dBm		580		mA
ACP	Adjacent channel power(±885KHz)				-29	dBc
NACP	Adjacent channel power(±1.98MHz)	Vref=3.0V			-42	dBc
Pin	Input Power	AMPS-mode,Po=31dBm		3		dBm
lct	Total Corrector Current	Vc1=Vc2=3.2V		820		mA
2sp/3sp	2nd/3rd Harmonics	Vref=3.0V			-30	dBc
Rxnoise	Noise in RX band			-140		dBc

Note1:  $Z_G=Z_L=50(\Omega)$ 

Note2: CDMA modulated signal based on IS-95 STD.

Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, circuits, (2) use of non-flammable material or (3) prevention against malfunction or mishap.